

Frequency Generator for Modem Systems

General Description

The ICS9117-01 is a low-cost, high-performance frequency generator designed to support fax/data modem systems. Datapump and UART clocks are synthesized from a microcontroller crystal using high-accuracy, low-jitter PLLs, meeting the frequency tolerance and -96dB signal-to-noise ratios required by 16-bit DSP modem systems. Fast output clock edge rates minimize board induced jitter.

Exact frequency multiplying ratios ensure better than ± 80 ppm frequency accuracy using a standard AT crystal with external load capacitors (typically 33pF $\pm 5\%$ for an 18pF series load crystal). Achieving ± 80 ppm over four years requires the crystal to have 20 ppm initial accuracy, ± 20 ppm temperature and ± 5 ppm/year aging coefficients.

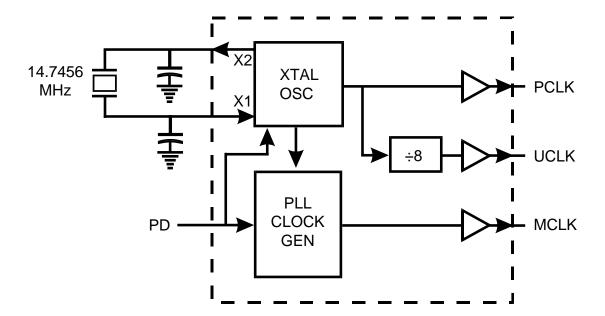
Features

- Generates the 14.7456 MHz microcontroller, 40.320 MHz datadump and 1.84320 UART clocks
- Less than ±80 ppm frequency variation including temperature, voltage, load and aging tolerances
- Single crystal reference minimizes crystal reliability and inventory issues
- 80 ps one sigma jitter maintains 16-bit performance
- Output rise/fall times less than 1.5 ns
- On-chip loop filter components
- 3.0 V 5.5 V supply range
- 8-pin, 150-mil SOIC package

Applications

 Specifically designed to support the high performance of fax/data modems

Block Diagram

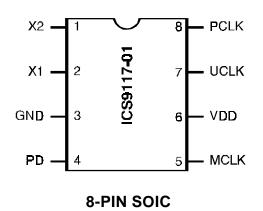


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Pin Configuration



Functionality

X1, X2 (MHz)	PD	PCLK (MHz)	MCLK (MHz)	UCLK (MHz)
14.7456	0	14.7456	40.320	1.8432
14.7456	1	Low	Low	Low

Pin Descriptions

PIN NUMBER	PIN NAME	ТҮРЕ	DESCRIPTION
1	X2	OUT	Drive to crystal.
2	X1	IN	Crystal or clock input.
3	GND	PWR	Power supply ground.
4	PD	IN	Power-down signal. Power-down all loops and oscillators.
5	MCLK	OUT	Datapump 40.32 MHz clock output.
6	VDD	PWR	+5V powersupply
7	UCLK	OUT	UART 1.84 MHz data clock output.
8	PCLK	OUT	Microcontroller 14.7 MHz clock output.

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Absolute Maximum Ratings

AV _{DD} , V _{DD} referenced to GND	7V
Operating temperature under bias	0 °C to +70 °C
Storage temperature	65 °C to +150 °C
Voltage on I/O pins referenced to GND	GND - 0.5V to $\text{V}_{\text{DD}} + 0.5 \text{V}$
Power dissipation	0.5 Watts

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Electrical Characteristics at 3.3V

Operating $V_{DD} = +3.0 \text{ V}$ to +3.7 V; $T_A = 0 \,^{\circ}\text{C}$ to $70 \,^{\circ}\text{C}$ unless otherwise stated

DC Characteristics							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Input Low Voltage	$V_{\rm IL}$		-	-	0.8	V	
Input High Voltage	V _{IH}		2.0	-	-	V	
Input Low Current	$I_{\Pi_{-}}$	V _{IN} =0V	-	-10.0	-25.0	μΑ	
Input High Current	$I_{ m IH}$	$V_{IN}=V_{DD}$	-	-	5.0	μΑ	
Output Low Voltage	V _{OL} *	I _{OL} =+10mA	-	0.15	0.4	V	
Output High Voltage	V _{OH} *	I _{OH} =-10mA	2.4	3.7	-	V	
Output Low Current	I _{OL} *	V=0.8V	20.0	35.0	-	mA	
Output High Current	I_{OH}^*	V=2.4V	-	-20.0	-10.0	mA	
Supply Current	I_{CC}	Unloaded	-	16.0	30.0	mA	
Pull-up Resistor Value	R _{pu} *		-	400.0	800.0	k ohm	
		AC Characteristics					
Rise Time	T_r^*	15o/f kiadm 0.8 to 2.0V	-	0.9	1.5	ns	
Fall Time	T_f^*	15pF load, 2.0 to 0.8V	-	1.2	3.0	ns	
Lock Time	T_L^*	15pFload, 20% to 80%			10.0	ms	
Duty Cycle	D _t *	15pFload @50% of VDD; ExceptREFCLK	45.0	50.0	55.0	%	
Duty Cycle	D _t *	15pF load@50% of VDD; Except REFCLK only	45.0	50.0	55.0	%	
Jitter, One Sigmea	T _{j1s} *	For all frequencies except REFCLK		70.0	100.0	ps	
Jitter, Absolute	T _{jab} *	Forall frequencies except REFCLK	-300.0		+300.0	ps	
Jitter, One Sigma	T _{i1s} *	REFCLK only		250.0	300.0	ps	
Jitter, Absolute	T _{iab} *	REFCLK only	-500.0		+500.0	ps	
Input FrequencyRange	F _i *		4.0		28.0	MHz	
Output Frequency Range	F _o *		11.7		74.0	MHz	
OutputMean Frequency Accuracy vs.Target	F _{oa} *	With 14.318 MHzinput	-80.0		+80.0	ppm	
Power-up Time	T _{pu} *	0 to 33.8 MHz		2.5	4.5	ms	
Crystal Input Capacitance	C _{inx} *	X1 (Pin 1) X2 (Pin 8)		18.0		pF	

^{*} Parameter is guaranteed by design and characterization. Not 100% tested in production.

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Absolute Maximum Ratings

AV _{DD} , V _{DD} referenced to GND	· 7V
Operating temperature under bias	0 °C to +70 °C
Storage temperature	-65 °C to +150 °C
Voltage on I/O pins referenced to GND	GND - 0.5V to $\text{V}_{\text{DD}} + 0.5 \text{V}$
Power dissipation	0.5 Watts

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

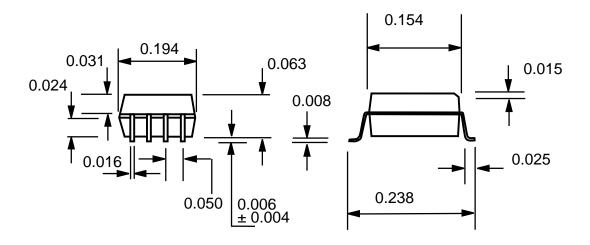
Electrical Characteristics at 5.0V

Operating V_{DD} = +4.5 V to +5.5V; T_A = 0 °C to 70°C unless otherwise stated

DC Characteristics							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Input Low Voltage	V _{IL}		-	-	0.8	V	
Input High Voltage	$V_{ m IH}$		2.0	=	-	V	
Input Low Current	$I_{ m IL}$	V _{IN} =0V	-	-7.0	-25.0	μΑ	
Input High Current	$I_{ m IH}$	$V_{IN}=V_{DD}$	-	-	5.0	μΑ	
Output Low Voltage	V _{OL} *	I _{OL} =+10mA	-	0.15	0.4	V	
Output High Voltage	V _{OH} *	I _{OH} =-10mA	4.0	4.2	-	V	
Output Low Current	I _{OL} *	V=0.8V	20.0	40.0	-	mA	
Output High Current	I _{OH} *	V=2.4V	-	-85.0	-65.0	mA	
Supply Current	I _{CC}	Unloaded	-	22.0	-35.0	mA	
Pull-up Resistor Value	R _{pu} *		-	400.0	800.0	k ohm	
	•	AC Characteristics	-	-			
Rise Time	T_r^*	15o/f kiadm 0.8 to 2.0V	-	0/8	1.5	ns	
Fall Time	T_f^*	15pF load, 2.0 to 0.8V	-	1.2	3.0	ns	
Lock Time	T_L*	15pFload, 20% to 80%			10.0	ms	
Duty Cycle	D _t *	15pFload @50% of VDD; Except REFCLK	45.0	50.0	55.0	%	
Duty Cycle	D _t *	15pF load@50% of VDD; REFCLK only	45.0	50.0	55.0	%	
Jitter, One Sigmea	T _{j1s} *	For all frequencies except REFCLK		80.0	120.0	ps	
Jitter, Absolute	Tjab*	Forall frequencies except REFCLK	-310.0		+300.0	ps	
Jitter, One Sigma	T _{j1s} *	REFCLK only		200.0	250.0	ps	
Jitter, Absolute	T _{jab} *	REFCLK only	-500.0		+500.0	ps	
Input FrequencyRange	Fi*		5.0		43.0	MHz	
Output Frequency Range	F _o *		14.0		114.0	MHz	
OutputMean Frequency Accuracy vs.Target	Foa*	With 14.318 MHzinput	-80.0		+80.0	ppm	
Power-up Time	T _{pu} *	0 to 33.8 MHz		2.5	4.5	ms	
Crystal Input Capacitance	C _{inx} *	X1 (Pin 1), X2 (Pin 8)		18.0		pF	

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8-Pin SOIC

Ordering Information

ICS9117M-01

Example:

